ΡΛΝ	JIT
	SEMI
	CONDUCTOR

#### 20V P-Channel Enhancement Mode MOSFET

Voltage

### Features

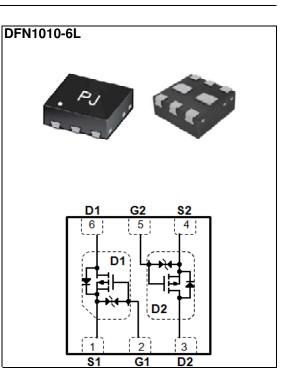
• Advanced Trench Process Technology

-20 V

• Specially Designed for Switch Load, PWM Application, etc.

Current

- ESD Protected
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard



#### **Mechanical Data**

- Case : DFN1010-6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.000045 ounces, 0.0013 grams

#### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

-600mA

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage	V <sub>DS</sub>	-20	V		
Gate-Source Voltage	V <sub>GS</sub>	<u>+</u> 8			
Continuous Drain Current (Note 4)		lь	-600	mA	
Pulsed Drain Current (Note 1)	ldм	-1200			
Power Dissipation	T <sub>a</sub> =25°C	PD	400	mW	
	Derate above 25°C		3.2	mW/°C	
Operating Junction and Storage Temperature Range		Tj,Tstg	-55~150	۰C	
Typical Thermal Resistance					
- Junction to Ambient (Note 3,4)		R <sub>0JA</sub>	312	°C/W	

Limited only By Maximum Junction Temperature





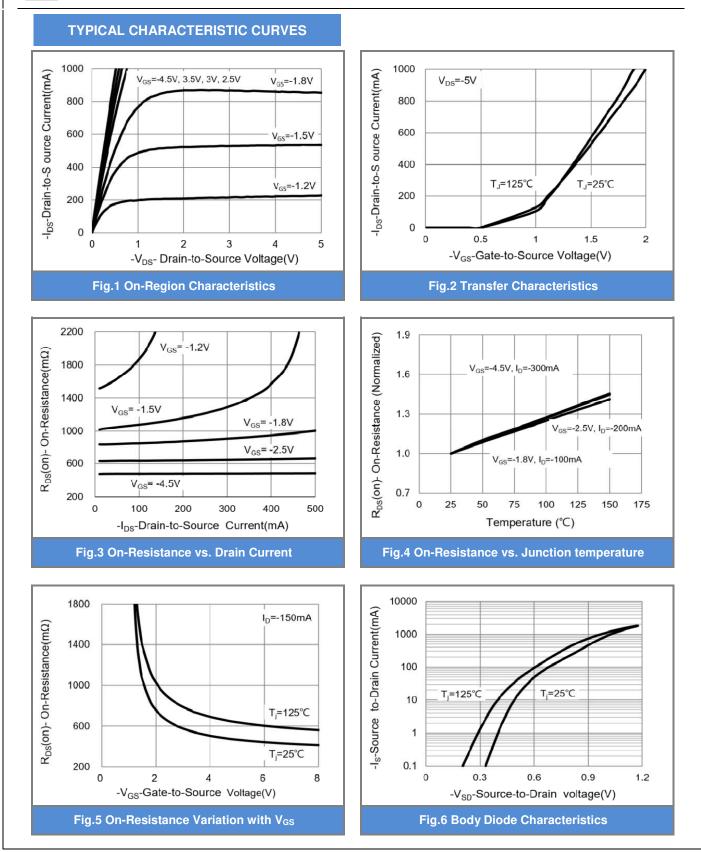
Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	-	- v
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.3	-0.6	-1	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-300mA	-	470	600	mΩ
		$V_{GS}$ =-2.5V, I <sub>D</sub> =-200mA	-	630	850	
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-100mA	-	810	1200	
		V <sub>GS</sub> =-1.5V, I <sub>D</sub> =-100mA	-	1020	1600	
		V <sub>GS</sub> =-1.2V, I <sub>D</sub> =-100mA	-	1670	3000	
Zero Gate Voltage Drain Current	IDSS	$V_{DS}$ =-20V, $V_{GS}$ =0V	-	-	-1	uA
Gate-Source Leakage Current	lgss	V <sub>GS=<u>+</u>8V, V<sub>DS</sub>=0V</sub>	-	-	<u>+</u> 10	
Dynamic (Note 5)						
Total Gate Charge	Qg	V <sub>DS</sub> =-10V, I <sub>D</sub> =-200mA, V <sub>GS</sub> =-4.5V <sup>(Note 2)</sup>	-	1.1	-	nC
Gate-Source Charge	Qgs		-	0.2	-	
Gate-Drain Charge	$Q_{gd}$		-	0.1	-	
Input Capacitance	Ciss		-	51	-	
Output Capacitance	Coss	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V,	-	15	-	pF
Reverse Transfer Capacitance	Crss	f=1MHZ	-	2.2	-	
Turn-On Delay Time	td <sub>(on)</sub>	101/ L 000m A	-	4.3	-	
Turn-On Rise Time	tr	$V_{DD}$ =-10V, I <sub>D</sub> =-200mA, V <sub>GS</sub> =-4.5V, R <sub>G</sub> =6Ω <sup>(Note 2)</sup>	-	20	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	33	-	
Turn-Off Fall Time	tf		-	25	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	ls		-	-	-200	mA
Diode Forward Voltage	V <sub>SD</sub>	Is=-200mA, V <sub>GS</sub> =0V	-	-0.85	-1	V

NOTES:

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. ReJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.







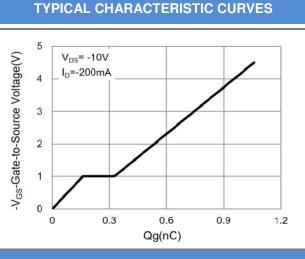


Fig.7 Gate-Charge Characteristics

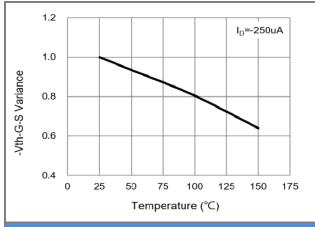
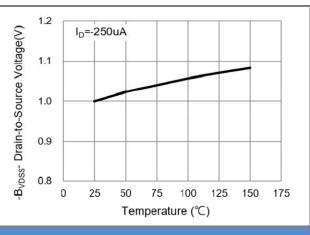


Fig.9 Threshold Voltage Variation with Temperature





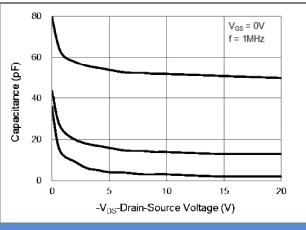


Fig.10 Capacitance vs. Drain-Source Voltage

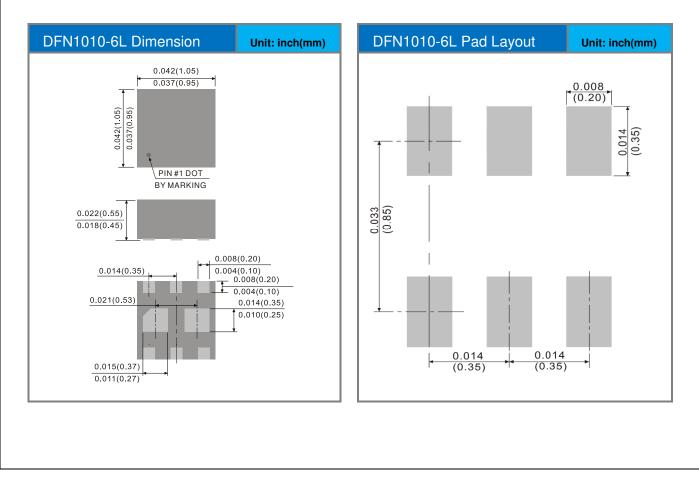




#### Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ1821_R1_00001	DFN1010-6L	5K pcs / 7" reel	821	Halogen free

#### **Packaging Information & Mounting Pad Layout**







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